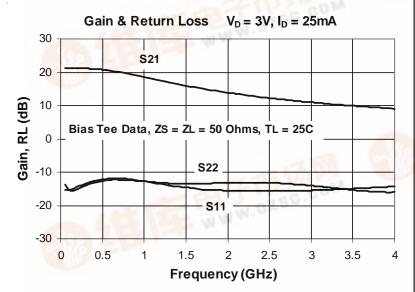
查询SGC-2486Z供应商

SIRENZA MICRODEVICES Product Description

Sirenza Microdevices' SGC-2486Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V supply, the SGC-2486Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SGC-2486Z is designed for high linearity 3V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.



SGC-2486Z

捷多邦,专业PCB打样工厂,24小时加急出货

50-4000 MHz Active Bias Silicon Germanium Cascadable Gain Block





Product Features

- Single Fixed 3V Supply
- No Dropping Resistor Required
- Patented Self-Bias Circuitry
- P1dB = 10.8 dBm at 1950 MHz
- OIP3 = 23.5 dBm at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

Parameters	Units	Frequency	Min.	Тур.	Max.
	190	850 MHz	18.4	19.9	21.4
Small Signal Gain	dB	1950 MHz	13.1	14.6	16.1
"- 77010 mM		2400 MHz		12.3	
Output Power at 1dB Compression		850 MHz		10.5	
	dBm	1950 MHz	9.8	10.8	
		2400 MHz		10.1	
Output Third Order Intercept Point		850 MHz		23.0	
	dBm	1950 MHz	21.5	23.5	1.4
		2400 MHz	87	25.0	
Input Return Loss	dB	1950 MHz	11.0	15.0	
Output Return Loss	dB	1950 MHz	9.5	13.5	
Noise Figure	dB	1930 MHz		3.3	4.3
V _D Device Operating Voltage				3	
IDevice Operating Current			21	25	29
Thermal Resistance (junction to lead)	°C/W			205	
is: $V_D = 3.0V$ $I_D = 25mA Typ.$ $T_L = 1$	25°C	OIP ₃ Tone	Spacing =	1MHz	
Bias Tee Data $Z_{S} =$	$Z_L = 50 \text{ Ohr}$	ns Pout per t	one = -5 <u>dB</u>	m	
	Small Signal GainOutput Power at 1dB CompressionOutput Power at 1dB CompressionOutput Third Order Intercept PointInput Return LossOutput Return LossOutput Return LossNoise FigureDevice Operating VoltageDevice Operating CurrentThermal Resistance (junction to lead)Device Vp = 3.0VIp = 25mA Typ.TL = 2	Small Signal GaindBOutput Power at 1dB CompressiondBmOutput Power at 1dB CompressiondBmOutput Third Order Intercept PointdBmInput Return LossdBOutput Return LossdBNoise FiguredBDevice Operating VoltageVDevice Operating CurrentmAThermal Resistance (junction to lead)°C/WSt $V_p = 3.0V$ $P_p = 25mA Typ.$ T_L = 25°C	Small Signal GaindB $850 \text{ MHz} \\ 1950 \text{ MHz} \\ 2400 \text{ MHz} \\ 1950 \text{ MHz}$	Small Signal GaindB $\begin{array}{c} 850 \text{ MHz} \\ 1950 \text{ MHz} \\ 2400 \text{ MHz} \end{array}$ 18.4Output Power at 1dB CompressiondBm $\begin{array}{c} 1950 \text{ MHz} \\ 1950 \text{ MHz} \\ 2400 \text{ MHz} \end{array}$ 9.8Output Power at 1dB CompressiondBm $\begin{array}{c} 1950 \text{ MHz} \\ 1950 \text{ MHz} \\ 2400 \text{ MHz} \end{array}$ 9.8Output Third Order Intercept PointdBm $\begin{array}{c} 1950 \text{ MHz} \\ 1950 \text{ MHz} \\ 2400 \text{ MHz} \end{array}$ 21.5Input Return LossdB1950 \text{ MHz} \\ 1950 \text{ MHz} \end{array}11.0Output Return LossdB1950 \text{ MHz} \\ 9.5 \end{array}9.5Noise FiguredB1930 \text{ MHz} \end{array}9.5Device Operating VoltageVVVDevice Operating CurrentmA21Thermal Resistance (junction to lead)°C/W $\begin{array}{c} OlP_3 \text{ Tore Spacing = } \end{array}$	Small Signal GaindB 850 MHz 18.4 19.9 Small Signal GaindB 1950 MHz 13.1 14.6 2400 MHz 13.1 14.6 2400 MHz 12.3 Output Power at 1dB CompressiondBm 850 MHz 9.8 $0utput Power at 1dB CompressiondBm1950 \text{ MHz}9.80utput Third Order Intercept PointdBm1950 \text{ MHz}21.50utput Third Order Intercept PointdB1950 \text{ MHz}21.50utput Return LossdB1950 \text{ MHz}21.50utput Return LossdB1950 \text{ MHz}11.00utput Return LossdB1950 \text{ MHz}3.30utput Return LossdB1930 \text{ MHz}3.30utput Return LossbB1930 \text{ MHz}21253.3253.30utput Return LossbB1930 \text{ MHz}21253.33.33.30utput Return LossbB1930 \text{ MHz}21253.33.33.3$

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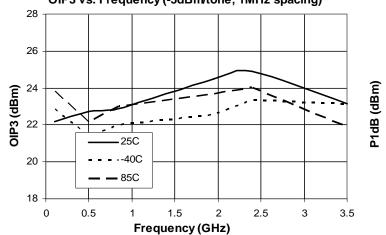




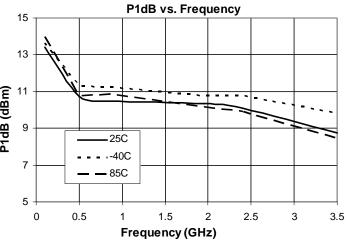
SGC-2486Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

Typical RF Performance at Key Operating Frequencies (Bias Tee)								
Symbol	Parameter	Unit	Frequency (MHz)					
			100	500	850	1950	2400	3500
G	Small Signal Gain	dB	21.5	21.0	19.9	14.6	12.3	9.6
OIP ₃	Output Third Order Intercept Point	dBm	22.0	22.5	23.0	23.5	25.0	23.0
P_{1dB}	Output Power at 1dB Compression	dBm	13.4	10.7	10.5	10.8	10.1	8.8
IRL	Input Return Loss	dB	14.5	11.5	12.5	15.0	16.5	15.0
ORL	Output Return Loss	dB	14.5	12.0	12.5	13.5	14.0	14.0
S ₁₂	Reverse Isolation	dB	23.5	25.0	24.5	20.0	19.0	17.5
NF	Noise Figure	dB	2.8	2.8	3.1	3.3	3.6	4.4
Test Conditions: $V_D = 3V$ $I_D = 25mA$ OIP_3 Tone Spacing = 1MHz, Pout per tone = -5 dBm $T_L = 25^{\circ}C$ $Z_S = Z_L = 50$ Ohms								

Typical Performance with Bias Tee, $V_{\rm D}$ = 3V, $I_{\rm D}$ = 25mA

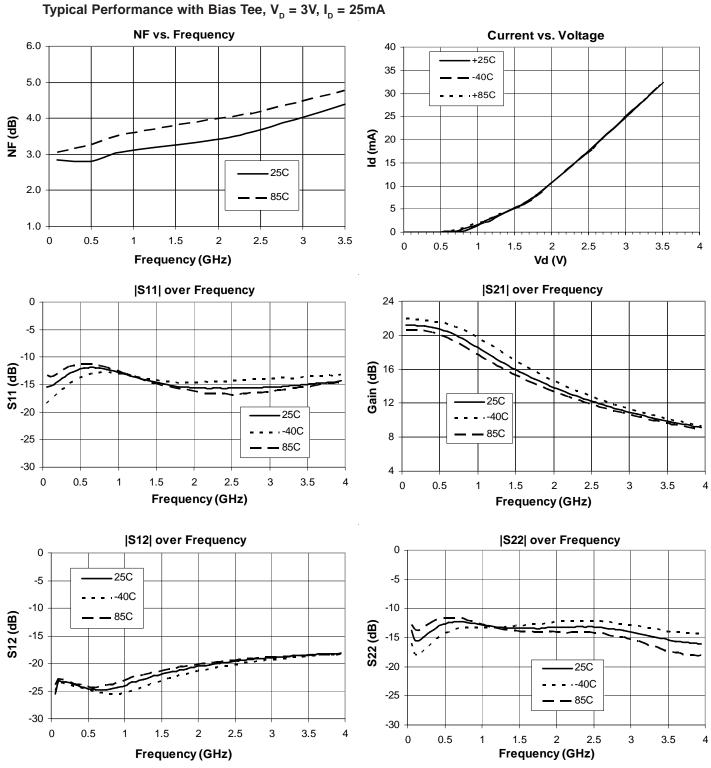


OIP3 vs. Frequency (-5dBm/tone, 1MHz spacing)



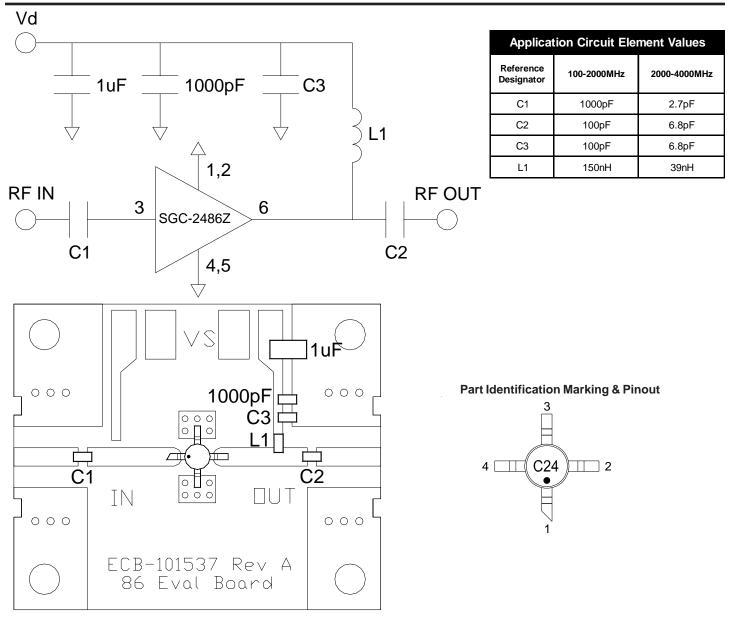
Absolute Maximum Ratings		Reliability & Qualification Information				
Parameter	Absolute Limit	Parameter R				
Max Device Current (I _{CE})	55 mA	ESD Rat	Class 1C			
Max Device Voltage (V _{CE})	4.5 V	Ν	MSL 1			
Max. RF Input Power* (See Note) Max. Junction Temp. (T _J)	+18 dBm +150°C	This product qualification report can be downloaded at www.sirenza.com				
Operating Temp. Range (T_L)	-40°C to +85°C		Caution: ESD sensitive			
Max. Storage Temp. $+150^{\circ}C$ *Note: Load condition, $Z_L = 50$ OhmsOperation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values			ckaging			
specified in the table on page one. Bias Conditions should also satisfy the $I_DV_D < (T_J - T_L) / R_{TH}$,						







SGC-2486Z 0.05-4.0 GHz Cascadeable MMIC Amplifier



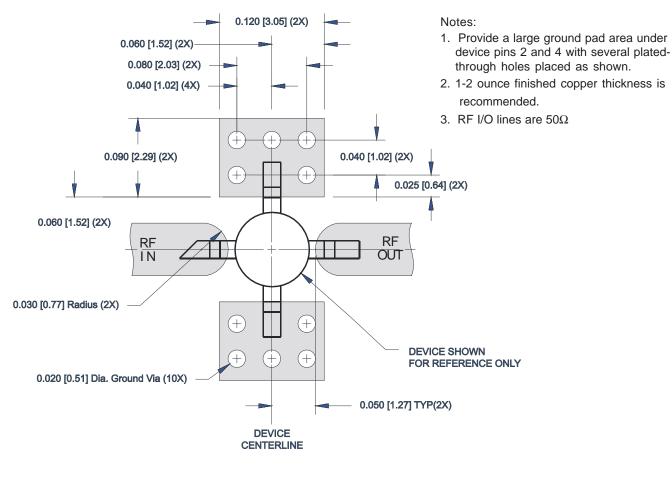
Pin #	Function	Description	Part / Evaluation Board Ordering Information			
1		RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation	Part Number	Description	Reel Size	Devices / Reel
		Connection to ground. Use via holes as close to the device	SGC-2486Z	Lead Free, RoHs Compliant	13"	3000
2,4 GND ground leads as possible to reduce ground inductance and achieve optimum RF performance	SGC-2486Z-EVB1	100-2000 MHz Evaluation Board	N/A	N/A		
	RF OUT /	RF output and bias pin. This pin requires the use of an	SGC-2486Z-EVB2	2000-4000 MHz Evaluation Board	N/A	N/A
3 D	DC BIAS	external DC blocking capacitor chosen for the frequency of operation.				



SGC-2486Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

86 PCB Pad Layout

Dimensions in inches [millimeters]



86 Nominal Package Dimensions

Dimensions in inches [millimeters] A link to the 86 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.

